NSN 5961-01-160-2932

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Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
T0-66
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
150.0 breakdown voltage, collector to emitter, sustained and 160.0 collector to emitter reverse voltage and 0.5 collector to emitter voltage
dc and 1.5 base to emitter voltage, dc
Current Rating Per Characteristic:
4.00 amperes source cutoff current and 2.00 amperes source cutoff current
Power Rating Per Characteristic:
50.0 watts small-signal input power, common-collector preset
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
2 pin
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0